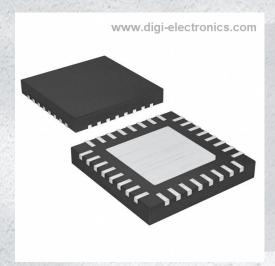


NB3V8312CMNG Datasheet



https://www.DiGi-Electronics.com

DiGi Electronics Part Number NB3V8312CMNG-DG

Manufacturer onsemi

Manufacturer Product Number NB3V8312CMNG

Description IC CLK BUFFER 1:12 250MHZ 32QFN

Detailed Description Clock Fanout Buffer (Distribution) IC 1:12 250 MHz 3

2-VFQFN Exposed Pad



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

DiGi is a global authorized distributor of electronic components.



Purchase and inquiry

Manufacturer Product Number: Manufacturer:			
NB3V8312CMNG	onsemi		
Series:	Product Status:		
	Active		
Type:	Number of Circuits:		
Fanout Buffer (Distribution)	1		
Ratio - Input:Output:	Differential - Input:Output:		
1:12	No/No		
Input:	Output:		
LVCMOS, LVTTL	LVCMOS		
Frequency - Max:	Voltage - Supply:		
250 MHz	1.6V ~ 3.465V		
Operating Temperature:	Mounting Type:		
-40°C ~ 85°C	Surface Mount		
Package / Case:	Supplier Device Package:		
32-VFQFN Exposed Pad	32-QFN (5x5)		
Base Product Number:			
NID2\/0212			

Environmental & Export classification

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	
8542.39.0001	

onsemi

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Ultra-Low Jitter, Low Skew 1:12 LVCMOS/LVTTL Fanout Buffer

NB3V8312C

The NB3V8312C is a high performance, low skew LVCMOS fanout buffer which can distribute 12 ultra-low jitter clocks from an LVCMOS/LVTTL input up to 250 MHz.

The 12 LVCMOS output pins drive 50 Ω series or parallel terminated transmission lines. The outputs can also be disabled to a high impedance (tri-stated) via the OE input, or enabled when High.

The NB3V8312C provides an enable input, CLK_EN pin, which synchronously enables or disables the clock outputs while in the LOW state. Since this input is internally synchronized to the input clock, changing only when the input is LOW, potential output glitching or runt pulse generation is eliminated.

Separate V_{DD} core and V_{DDO} output supplies allow the output buffers to operate at the same supply as the V_{DD} ($V_{DD} = V_{DDO}$) or from a lower supply voltage. Compared to single-supply operation, dual supply operation enables lower power consumption and output-level compatibility.

The V_{DD} core supply voltage can be set to 3.3 V, 2.5 V or 1.8 V, while the V_{DDO} output supply voltage can be set to 3.3 V, 2.5 V, or 1.8 V, with the constraint that $V_{DD} \ge V_{DDO}$.

This buffer is ideally suited for various networking, telecom, server and storage area networking, RRU LO reference distribution, medical and test equipment applications.

Features

• Power Supply Modes:

V _{DD} (Core)	/ V _{DDO} (Outputs)
3.3 V	/ 3.3 V
3.3 V	/ 2.5 V
3.3 V	/ 1.8 V
2.5 V	/ 2.5 V
2.5 V	/ 1.8 V
1.8 V	/ 1.8 V

- 250 MHz Maximum Clock Frequency
- Accepts LVCMOS, LVTTL Clock Inputs
- LVCMOS Compatible Control Inputs
- 12 LVCMOS Clock Outputs
- Synchronous Clock Enable
- Output Enable to High Z State Control
- 150 ps Max. Skew Between Outputs
- Temp. Range -40°C to +85°C
- 32-pin LQFP and QFN Packages
- These are Pb-Free Devices







QFN32 MN SUFFIX CASE 488AM

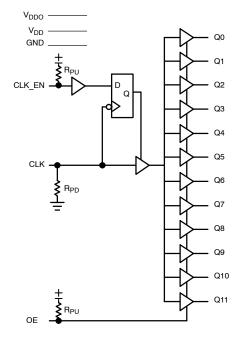


Figure 1. Simplified Logic Diagram

ORDERING AND MARKING INFORMATION

See detailed ordering and shipping information on page 9 of this data sheet.

Applications

- Networking
- Telecom
- Storage Area Network

End Products

- Servers
- Routers
- Switches

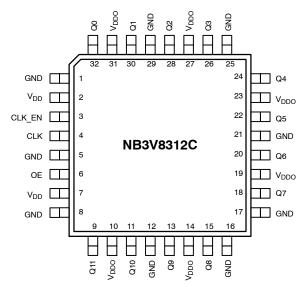


Figure 2. LQFP-32 Pinout Configuration (Top View)

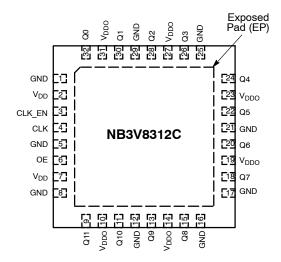


Figure 3. QFN32 Pinout Configuration (Top View)

Table 1. PIN DESCRIPTION

Pin	Name	I/O	Open Default	Description
1, 5, 8, 12, 16, 17, 21, 25, 29	GND	Power		Ground, Negative Power Supply
2, 7	VDD	Power		Positive Supply for Core and Inputs
3	CLK_EN	Input	High	Synchronous Clock Enable Input. When High, outputs are enabled. When Low, outputs are disabled Low. Internal Pullup Resistor.
4	CLK	Input	Low	Single-ended Clock input; LVCMOS/LVTTL. Internal Pull-down Resistor.
6	OE	Input	High	Output Enable. Internal Pullup Resistor.
9, 11, 13, 15, 18, 20, 22, 24, 26, 28, 30, 32	Q11, Q10, Q9, Q8, Q7, Q6, Q5, Q4, Q3, Q2, Q1, Q0	Output		Single-ended LVCMOS/LVTTL outputs
10, 14, 19, 23, 27, 31	VDDO	Power		Positive Supply for Outputs
-	EP	-	-	The Exposed Pad (EP) on the package bottom is thermally connected to the die for improved heat transfer out of package. The exposed pad must be attached to a heat–sinking conduit. The pad is connected to the die and must only be connected electrically to GND on the PC board.

All VDD, VDDO and GND pins must be externally connected to a power supply to guarantee proper operation. Bypass each supply pin with 0.01 μF to GND.

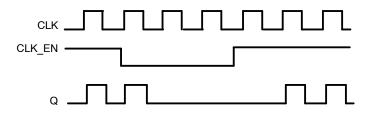


Figure 4. CLK_EN Control Timing Diagram

Table 2. OE, CLK_EN FUNCTION TABLES

Inputs	Outputs		
OE	Q[0:11]		
0	Х	Х	Hi–Z
1	0	Х	Low
1	1	0	Low
1	1	1	High

^{2.} The CLK_EN control input synchronously enables or disables the outputs as shown in Figure 4. This control latches on the falling edge of the selected input CLK. When CLK_EN is LOW, the outputs are disabled in a LOW state. When CLK_EN is HIGH, the outputs are enabled as shown. CLK_EN to CLK Set up and Hold times must be satisfied.

Table 3. ATTRIBUTES (Note 3)

	Value			
Internal Input Pullup (R _{PU}) and Pulldow	50 kΩ			
Input Capacitance, C _{IN}		4 pF		
Power Dissipation Capacitance, C _{PD} (p	er Output)	20 pF		
R _{OUT}		8 Ω		
ESD Protection	Human Body Model Machine Model	> 1.5 kV > 200 V		
Moisture Sensitivity (Note 3)	LQFP QFN	Level 2 Level 1		
Flammability Rating Oxygen Index		UL-94 code V-0 A 1/8" 28 to 34		
Transistor Count	464 Devices			
Meets or exceeds JEDEC Spec EIA/JESD78 IC Latchup Test				

^{3.} For additional information, see Application Note AND8003/D.

Table 4. MAXIMUM RATINGS (Note 4)

Symbol	Parameter	Condi	tion	Rating	Unit
V _{DD} / V _{DDO}	Positive Power Supply	GND = 0 V		4.6	V
VI	Input Voltage			$-0.5 \le V_{I} \le V_{DD} + 0.5$	V
T _{stg}	Storage Temperature Range			−65 to +150	°C
θ_{JA}	Thermal Resistance (Junction-to-Ambient) (Note 5)	0 lfpm 500 lfpm	LQFP-32 LQFP-32	80 55	°C/W
θЈС	Thermal Resistance (Junction-to-Case) (Note 5)	Standard Board	LQFP-32 LQFP-32	12–17	°C/W
$\theta_{\sf JA}$	Thermal Resistance (Junction-to-Ambient) (Note 5)	0 lfpm 500 lfpm	QFN – 32 QFN – 32	31 27	°C/W
θJC	Thermal Resistance (Junction-to-Case) (Note 5)	Standard Board	QFN - 32	12	°C/W

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Table 5. LVCMOS/LVTTL DC CHARACTERISTICS ($T_A = -40^{\circ}C$ to $+85^{\circ}C$)

Symbol	Chara	cteristics	Conditions	Min	Тур	Max	Unit
	Input High Voltage		V _{DD} = 3.465 V	2.0		V _{DD} + 0.3	V
V _{IH}			V _{DD} = 2.625 V	1.7		V _{DD} + 0.3	V
			V _{DD} = 2.0 V	0.65 x V _{DD}		V _{DD} + 0.3	V
			V _{DD} = 3.465 V	-0.3		1.3	V
V_{IL}	Input Low Vol	tage	V _{DD} = 2.625 V	-0.3		0.7	V
- 12	input Low Voitage		V _{DD} = 2.0 V	-0.3		0.35 x V _{DD}	V
	Input High	CLK	V V 0.405 V 27 0.005 V 27 0.0 V			150	
I _{IH}	Current	OE, CLK_EN	V _{DD} = V _{IN} = 3.465 V or 2.625 V or 2.0 V			5	μΑ
	Input Low	CLK	V 2.465 V oz 0.605 V oz 0.0 V V 0.V	-5			
I _{IL}	Current	OE, CLK_EN	V _{DD} = 3.465 V or 2.625 V or 2.0 V, V _{IN} = 0 V	-150			μΑ
			V _{DDO} = 3.3 V ±5%	2.6			
			V _{DDO} = 2.5 V ±5%	1.8			
.,		/ II	$V_{DDO} = 2.5 \text{ V} \pm 5\%; I_{OH} = -1 \text{ mA}$	2.0			.,
V _{OH}	Output High V	/oltage (Note 6)	V _{DDO} = 1.8 V ±0.2 V	V _{DD} – 0.4			V
			V_{DDO} = 1.8 V ±0.2 V; I_{OH} = -100 μA	V _{DD} – 0.2			
	Output Low Voltage (Note 6)		V _{DDO} = 3. 3V ±5%			0.5	V
			V _{DDO} = 2.5 V ±5%			0.45	
V_{OL}			$V_{DDO} = 2.5 \text{ V } \pm 5\%; I_{OL} = 1 \text{ mA}$			0.4	
			V _{DDO} = 1.8 V ±0.2 V			0.35	
			V _{DDO} = 1.8 V ±0.2 V; I _{OL} = 100 μA			0.2	

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm.

^{4.} Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and not valid simultaneously. If stress limits are exceeded device functional operation is not implied, damage may occur and reliability may be affected.

^{5.} JEDEC standard multilayer board – 2S2P (2 signal, 2 power).

^{6.} Outputs terminated 50 Ω to $\mbox{V}_{\mbox{DDO}}/2$ unless otherwise specified. See Figure 7.

Table 6. POWER SUPPLY DC CHARACTERISTICS, $(T_A = -40^{\circ}C \text{ to } +85^{\circ}C)$

V _{DD} (Core)	V _{DDO} (Outputs)	Min	Тур	Max	Unit
3.3 V ±5%	3.3 V ±5%			10	mA
3.3 V ±5%	2.5 V ±5%			10	mA
3.3 V ±5%	1.8 V ± 0.2V			10	mA
2.5 V ±5%	2.5 V ±5%			10	mA
2.5 V ±5%	1.8 V ± 0.2V			10	mA
1.8 V ± 0.2 V	1.8 V ± 0.2V			10	mA

Table 7. AC CHARACTERISTICS ($T_A = -40$ °C to +85°C) (Note 7)

Symbol	Characteristic	Min	Тур	Max	Unit
f _{MAX}	$\begin{array}{c} \text{Maximum Operating Frequency} & V_{DD} / V_{DDO} \\ 3.3 \text{V} \pm 5\% / 3.3 \text{V} \pm 5\% \\ 3.3 \text{V} \pm 5\% / 2.5 \text{V} \pm 5\% \\ 3.3 \text{V} \pm 5\% / 1.8 \text{V} \pm 0.2 \text{V} \\ 2.5 \text{V} \pm 5\% / 2.5 \text{V} \pm 5\% \\ 2.5 \text{V} \pm 5\% / 1.8 \text{V} \pm 0.2 \text{V} \\ 1.8 \text{V} \pm 0.2 \text{V} / 1.8 \text{V} \pm 0.2 \text{V} \end{array}$	250 250 200 250 200 200			MHz
t _{pLH}	Propagation Delay, Low to High; (Note 8) $ \begin{array}{c} V_{DD} / V_{DDO} \\ 3.3 \ V \pm 5\% / 3.3 \ V \pm 5\% \\ 3.3 \ V \pm 5\% / 2.5 \ V \pm 5\% \\ 3.3 \ V \pm 5\% / 1.8 \ V \pm 0.2 \ V \\ 2.5 \ V \pm 5\% / 2.5 \ V \pm 5\% \\ 2.5 \ V \pm 5\% / 1.8 \ V \pm 0.2 \ V \\ 1.8 \ V \pm 0.2 \ V / 1.8 \ V \pm 0.2 \ V \end{array} $	0.9 1.0 1.0 1.3 1.3 2.4		2.2 2.3 3.0 3.1 3.5 4.2	ns
tjit	$ \begin{array}{llllllllllllllllllllllllllllllllllll$		30 40 50 20 100 130		fs
t _{sk(o)}	Output–to–output skew; (Note 9); Figure 6 $\begin{array}{c} V_{DD} / V_{DDO} \\ 3.3 \ V \pm 5\% / 3.3 \ V \pm 5\% \\ 3.3 \ V \pm 5\% / 2.5 \ V \pm 5\% \\ 3.3 \ V \pm 5\% / 1.8 \ V \pm 0.2 \ V \\ 2.5 \ V \pm 5\% / 2.5 \ V \pm 5\% \\ 2.5 \ V \pm 5\% / 1.8 \ V \pm 0.2 \ V \\ 1.8 \ V \pm 0.2 \ V / 1.8 \ V \pm 0.2 \ V \end{array}$			125 135 145 150 150 140	ps
t _{sk(pp)}	Part-to-Part Skew; (Note 10) $ \begin{array}{c} V_{DD} / V_{DDO} \\ 3.3 V \pm 5\% / 3.3 V \pm 5\% \\ 3.3 V \pm 5\% / 2.5 V \pm 5\% \\ 3.3 V \pm 5\% / 1.8 V \pm 0.2 V \\ 2.5 V \pm 5\% / 2.5 V \pm 5\% \\ 2.5 V \pm 5\% / 1.8 V \pm 0.2 V \\ 1.8 V \pm 0.2 V / 1.8 V \pm 0.2 V \end{array} $			250 250 250 250 250 250 250	ps

All parameters measured at $f_{\mbox{\scriptsize MAX}}$ unless noted otherwise.

Outputs loaded with 50 Ω to V_{DDO}/2; see Figure 7. CLOCK input with 50% duty cycle; minimum input amplitude = 1.2 V at V_{DD} = 3.3 V, 1.0 V at V_{DD} = 2.5 V, V_{DD}/2 at V_{DD} = 1.8 V.
 Measured from the V_{DD}/2 of the input to V_{DDO}/2 of the output.
 Defined as skew between outputs at the same supply voltage and with equal load conditions. Measured at V_{DDO}/2.
 Defined as skew between outputs on different devices operating at the same supply voltage and with equal load conditions.

Using the same type of input on each device, the output is measured at V_{DDO}/2.

^{11.} Clock input with 50% duty cycles, rail-to-rail amplitude and $t_r/t_f = 500$ ps.

Table 7. AC CHARACTERISTICS ($T_A = -40^{\circ}\text{C} \text{ to } +85^{\circ}\text{C}$) (Note 7) (continued)

Symbol	Characteristic	Min	Тур	Max	Unit
t _r /t _f	Output rise and fall times $\begin{array}{c} V_{DD} / V_{DDO} \\ 3.3 \ V \pm 5\% / 3.3 \ V \pm 5\% \\ 3.3 \ V \pm 5\% / 2.5 \ V \pm 5\% \\ 3.3 \ V \pm 5\% / 1.8 \ V \pm 0.2 \ V \\ 2.5 \ V \pm 5\% / 2.5 \ V \pm 5\% \\ 2.5 \ V \pm 5\% / 1.8 \ V \pm 0.2 \ V \\ 1.8 \ V \pm 0.2 \ V / 1.8 \ V \pm 0.2 \ V \end{array}$	200 200 200 200 200 200 200		700 700 700 700 700 700 800	ps
ODC	$\begin{array}{l} \text{Output Duty Cycle (Note 11)} & V_{DD} / V_{DDO} \\ f \leq 200 \text{ MHz, } 3.3 \text{ V} \pm 5\% / 3.3 \text{ V} \pm 5\% \\ f \leq 150 \text{ MHz, } 3.3 \text{ V} \pm 5\% / 2.5 \text{ V} \pm 5\% \\ f \leq 100 \text{ MHz, } 3.3 \text{ V} \pm 5\% / 1.8 \text{ V} \pm 0.2 \text{ V} \\ f \leq 150 \text{ MHz, } 2.5 \text{ V} \pm 5\% / 2.5 \text{ V} \pm 5\% \\ f \leq 100 \text{ MHz, } 2.5 \text{ V} \pm 5\% / 1.8 \text{ V} \pm 0.2 \text{ V} \\ f \leq 100 \text{ MHz, } 2.5 \text{ V} \pm 5\% / 1.8 \text{ V} \pm 0.2 \text{ V} \\ f \leq 100 \text{ MHz, } 1.8 \text{ V} \pm 0.2 \text{ V} / 1.8 \text{ V} \pm 0.2 \text{ V} \end{array}$	45 45 45 45 45 45		55 55 55 55 55 55	%

All parameters measured at f_{MAX} unless noted otherwise.

- Outputs loaded with 50 ½ to V_{DDO}/2; see Figure 7. CLOCK input with 50% duty cycle; minimum input amplitude = 1.2 V at V_{DD} = 3.3 V, 1.0 V at V_{DD} = 2.5 V, V_{DD}/2 at V_{DD} = 1.8 V.
 Measured from the V_{DD}/2 of the input to V_{DDO}/2 of the output.
 Defined as skew between outputs at the same supply voltage and with equal load conditions. Measured at V_{DDO}/2.

- 10. Defined as skew between outputs on different devices operating at the same supply voltage and with equal load conditions. Using the same type of input on each device, the output is measured at $V_{DDO}/2$.
- 11. Clock input with 50% duty cycles, rail-to-rail amplitude and $t_r/t_f = 500$ ps.

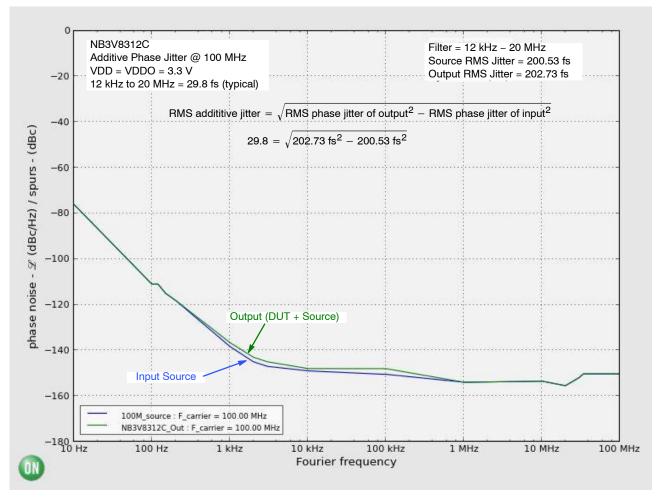


Figure 5. Typical Phase Noise Plot at f_{carrier} = 100 MHz at an Operating Voltage of 3.3 V, Room Temperature

The above phase noise data was captured using Agilent E5052A/B. The data displays the input phase noise and output phase noise used to calculate the additive phase jitter at a specified integration range. The RMS Phase Jitter contributed by the device (integrated between 12 kHz and 20 MHz) is 29.8 fs.

The additive phase jitter performance of the fanout buffer is highly dependent on the phase noise of the input source.

To obtain the most accurate additive phase noise measurement, it is vital that the source phase noise be notably lower than that of the DUT. If the phase noise of the source is greater than the device under test output, the source noise will dominate the additive phase jitter calculation and lead to an artificially low result for the additive phase noise measurement within the integration range. The Figure above is a good example of the NB3V8312C source generator phase noise having a significantly higher floor such that the DUT output results in an additive phase jitter of 29.8 fs.

RMS addititive jitter =
$$\sqrt{\text{RMS phase jitter of output}^2 - \text{RMS phase jitter of input}^2}$$

 $29.8 = \sqrt{202.73 \, \text{fs}^2 - 200.53 \, \text{fs}^2}$

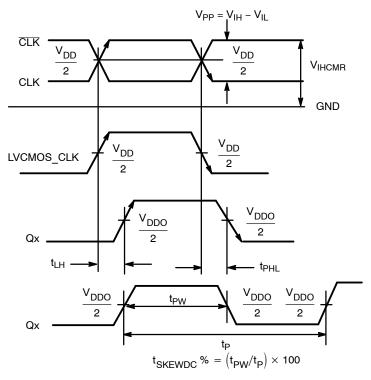


Figure 6. AC Reference Measurement

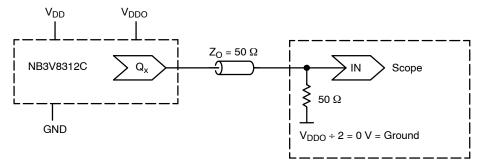
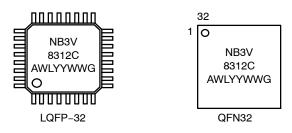


Figure 7. Typical Device Evaluation and Termination Setup - See Table 8

Table 8. TEST SUPPLY SETUP. V_{DDO} SUPPLY MAY BE CENTERED ON 0.0 V (SCOPE GND) TO PERMIT DIRECT CONNECTION INTO "50 Ω TO GND" SCOPE MODULE. V_{DD} SUPPLY TRACKS DUT GND PIN

Spec Condition:	V _{DD} Test Setup	VDDO Test Setup	GND Pin Test Setup
V _{DD} = 3.3 V ±5%, V _{DDO} = 3.3 V ±5%	+1.65 ±5%	+1.65 V ±5%	-1.65 V ±5%
$V_{DD} = 3.3 \text{ V} \pm 5\%, V_{DDO} = 2.5 \text{ V} \pm 5\%$	+2.05 V ±5%	+1.25 V ±5%	-1.25 V ±5%
$V_{DD} = 3.3 \text{ V} \pm 5\%, V_{DDO} = 1.8 \text{ V} \pm 5\%$	+2.4 V ±5%	+0.9 V ±0.1 V	-0.9 V ±0.1 V
V _{DD} = 2.5 V ±5%, V _{DDO} O = 2.5 V ±5%	+1.25 V ±5%	+1.25 V ±5%	-1.25 V ±5%
$V_{DD} = 2.5 \text{ V} \pm 5\%, V_{DDO} = 1.8 \text{ V} \pm 0.2 \text{ V}$	+1.6 V ±5%	+0.9 V ±0.1 V	-0.9 V ±0.1 V
V _{DD} = 1.8 V ±0.2 V, V _{DDO} = 1.8 V ±0.2 V	+0.9 V ±0.1 V	+0.9 V ±0.1 V	−0.9 V ±0.1 V

MARKING DIAGRAMS*



A = Assembly Location WL = Wafer Lot

YY = Year
WW = Work Week
G = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping [†]	
NB3V8312CFAG	LQFP-32 (Pb-Free)	250 Units / Tray	
NB3V8312CFAR2G	LQFP-32 (Pb-Free)	2000 / Tape & Reel	
NB3V8312CMNG	QFN32 (Pb-Free)	74 Units / Tube	
NB3V8312CMNR4G	QFN32 (Pb-Free)	1000 / Tape & Reel	

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, <u>BRD8011/D</u>.

^{*}For additional marking information, refer to Application Note <u>AND8002/D</u>.



0.10 С

NOTE 4

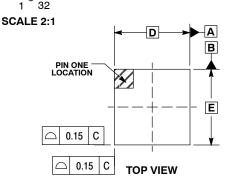
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MECHANICAL CASE OUTLINE

PACKAGE DIMENSIONS

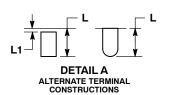


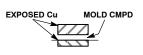
DATE 23 OCT 2013



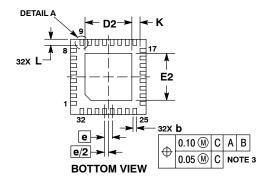
DETAIL B

SIDE VIEW

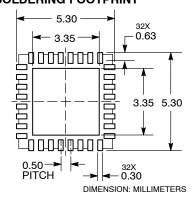




DETAIL B ALTERNATE CONSTRUCTION



RECOMMENDED SOLDERING FOOTPRINT*

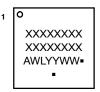


*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

- 1. DIMENSIONS AND TOLERANCING PER
- ASME Y14.5M, 1994. CONTROLLING DIMENSION: MILLIMETERS.
- DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.30MM FROM THE TERMINAL TIP.
 COPLANARITY APPLIES TO THE EXPOSED
- PAD AS WELL AS THE TERMINALS.

	MILLIMETERS		
DIM	MIN	MAX	
Α	0.80	1.00	
A1		0.05	
A3	0.20 REF		
b	0.18	0.30	
D	5.00 BSC		
D2	2.95	3.25	
E	5.00 BSC		
E2	2.95	3.25	
е	0.50 BSC		
K	0.20		
L	0.30	0.50	
11		0.15	

GENERIC MARKING DIAGRAM*



XXXXX = Specific Device Code

= Assembly Location = Wafer Lot WL

= Year VV WW = Work Week = Pb-Free Package

(Note: Microdot may be in either loca-

tion)
*This information is generic. Please refer to device data sheet for actual part marking.

Pb-Free indicator, "G" or microdot " ■", may or may not be present.

DOCUMENT NUMBER:	98AON20032D	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.	
DESCRIPTION:	QFN32 5x5 0.5P		PAGE 1 OF 1

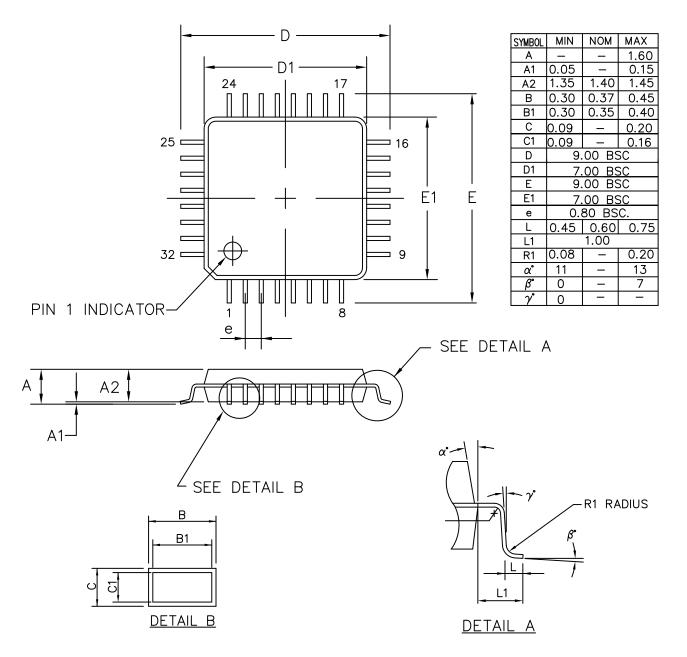
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